



## APTD3216SF4C-P22 3.2 x 1.6 mm Infrared Emitting Diode

### DESCRIPTION

- SF4 Made with Gallium Aluminum Arsenide Infrared Emitting diodes

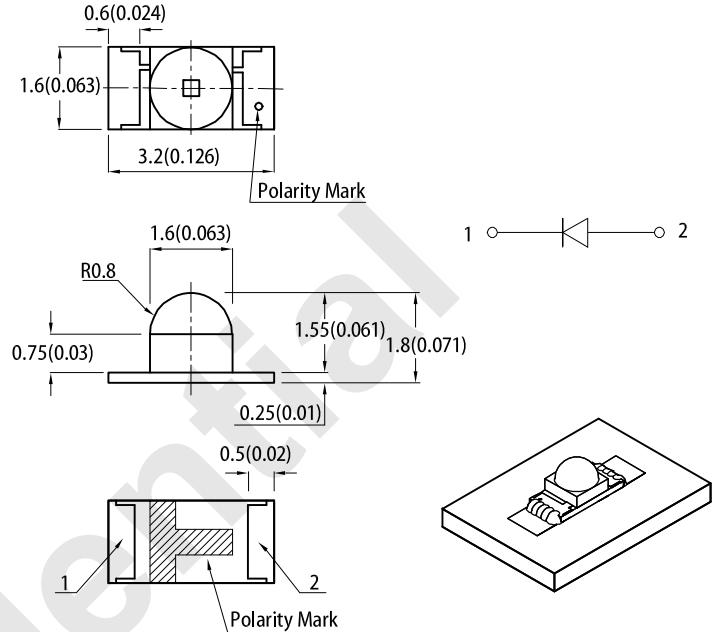
### FEATURES

- 3.2 mm x 1.6mm SMD LED, 1.8 mm thickness
- Mechanically and spectrally matched to phototransistor
- Package: 2000 pcs / reel
- Moisture sensitivity level: 3
- RoHS compliant

### APPLICATIONS

- Infrared Illumination for cameras
- Machine vision systems
- Surveillance systems
- Industrial electronics
- IR data transmission
- Remote control

### PACKAGE DIMENSIONS



### RECOMMENDED SOLDERING PATTERN (units : mm; tolerance : ± 0.1)



#### Notes:

1. All dimensions are in millimeters (inches).
2. Tolerance is ±0.2(0.008") unless otherwise noted.
3. The specifications, characteristics and technical data described in the datasheet are subject to change without prior notice.
4. The device has a single mounting surface. The device must be mounted according to the specifications.

### SELECTION GUIDE

Part Number	Emitting Color (Material)	Lens Type	Po (mW/sr) @ 20mA [2]		Viewing Angle [1]
			Min.	Typ.	2θ1/2
APTD3216SF4C-P22	Infrared (GaAlAs)	Water Clear	1.6	4	40°

Notes:  
 1. θ1/2 is the angle from optical centerline where the luminous intensity is 1/2 of the optical peak value.  
 2. Radiant Intensity / luminous flux: +/-15%.  
 3. Radiant intensity value is traceable to CIE127-2007 standards.

**ELECTRICAL / OPTICAL CHARACTERISTICS at T<sub>A</sub>=25°C**

Parameter	Symbol	Emitting Color	Value		Unit
			Typ.	Max.	
Wavelength at Peak Emission I <sub>F</sub> = 20mA	λ <sub>peak</sub>	Infrared	880	-	nm
Spectral Bandwidth at 50% Φ REL MAX I <sub>F</sub> = 20mA	Δλ	Infrared	50	-	nm
Capacitance	C	Infrared	90	-	pF
Forward Voltage I <sub>F</sub> = 20mA	V <sub>F</sub> <sup>[1]</sup>	Infrared	1.3	1.6	V
Reverse Current (V <sub>R</sub> = 5V)	I <sub>R</sub>	Infrared	-	10	uA
Temperature Coefficient of Wavelength I <sub>F</sub> = 20mA, -10°C ≤ T ≤ 85°C	TC <sub>λ</sub>	Infrared	0.3	-	nm/°C
Temperature Coefficient of V <sub>F</sub> I <sub>F</sub> = 20mA, -10°C ≤ T ≤ 85°C	TC <sub>V</sub>	Infrared	-1.3	-	mV/°C

## Notes:

1. Forward voltage: ±0.1V.
2. Wavelength value is traceable to CIE127-2007 standards.
3. Excess driving current and / or operating temperature higher than recommended conditions may result in severe light degradation or premature failure.

**ABSOLUTE MAXIMUM RATINGS at T<sub>A</sub>=25°C**

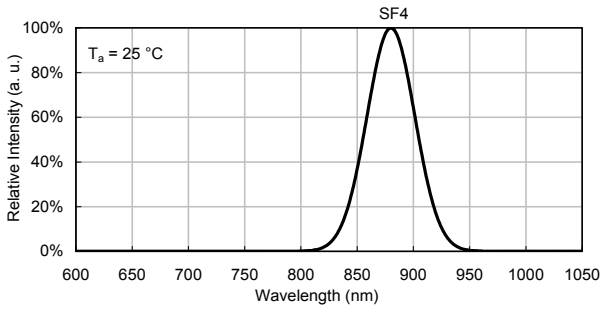
Parameter	Symbol	Value	Unit
Power Dissipation	P <sub>D</sub>	85	mW
Reverse Voltage	V <sub>R</sub>	5	V
Junction Temperature	T <sub>j</sub>	125	°C
Operating Temperature	T <sub>op</sub>	-40 to +85	°C
Storage Temperature	T <sub>stg</sub>	-40 to +85	°C
DC Forward Current	I <sub>F</sub>	50	mA
Peak Forward Current	I <sub>FM</sub> <sup>[1]</sup>	1200	mA
Electrostatic Discharge Threshold (HBM)	-	8000	V
Thermal Resistance (Junction / Ambient)	R <sub>th JA</sub> <sup>[2]</sup>	420	°C/W
Thermal Resistance (Junction / Solder point)	R <sub>th JS</sub> <sup>[2]</sup>	295	°C/W

## Notes:

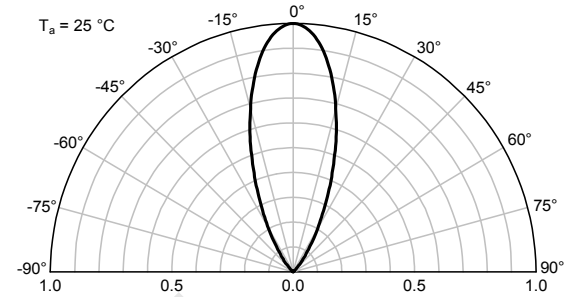
1. 1/100 Duty Cycle, 10μs Pulse Width.
2. R<sub>th JA</sub>, R<sub>th JS</sub> Results from mounting on PC board FR4 (pad size ≥ 16 mm<sup>2</sup> per pad).
3. Relative humidity levels maintained between 40% and 60% in production area are recommended to avoid the build-up of static electricity – Ref JEDEC/JESD625-A and JEDEC/J-STD-033.

## TECHNICAL DATA

### RELATIVE INTENSITY vs. WAVELENGTH

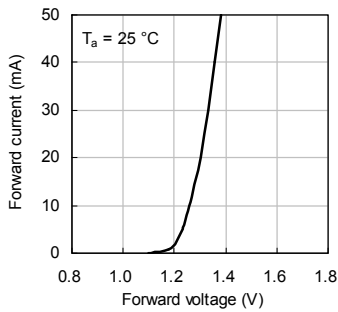


### SPATIAL DISTRIBUTION

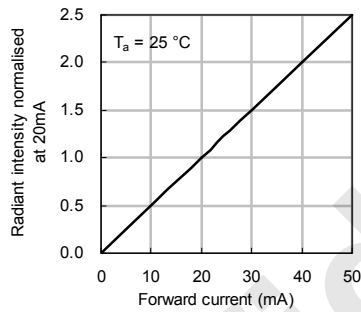


## INFRARED

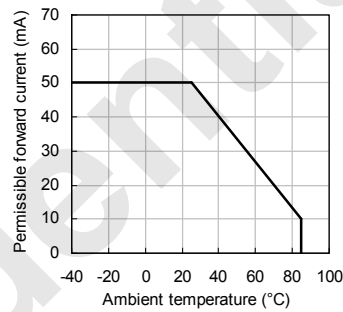
Forward Current vs. Forward Voltage



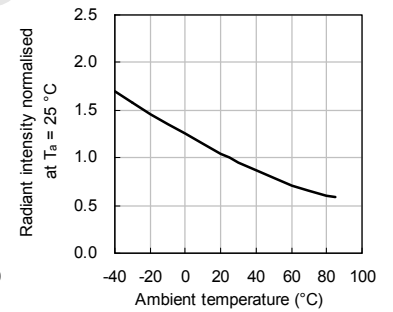
Radiant Intensity vs. Forward Current



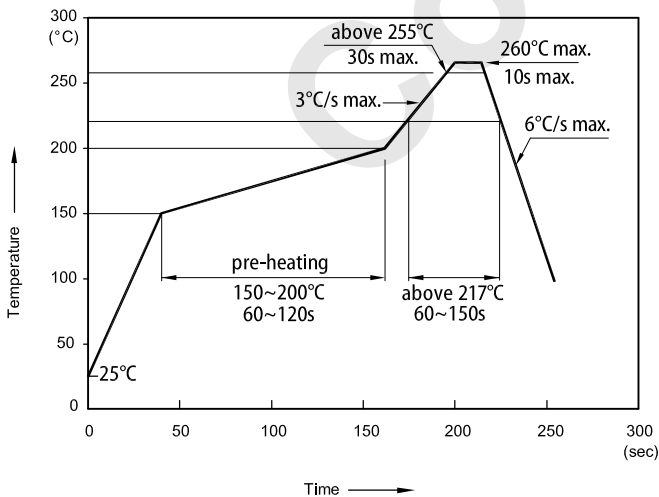
Forward Current Derating Curve



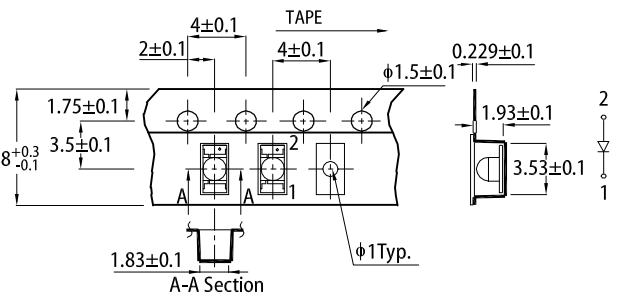
Radiant Intensity vs. Ambient Temperature



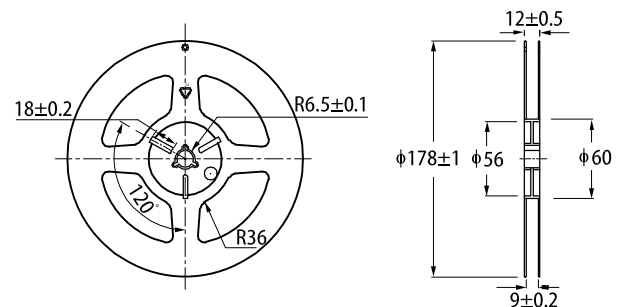
### REFLOW SOLDERING PROFILE for LEAD-FREE SMD PROCESS



### TAPE SPECIFICATIONS (units : mm)

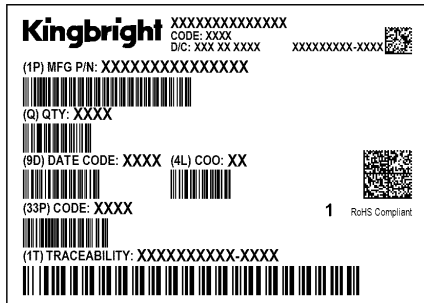
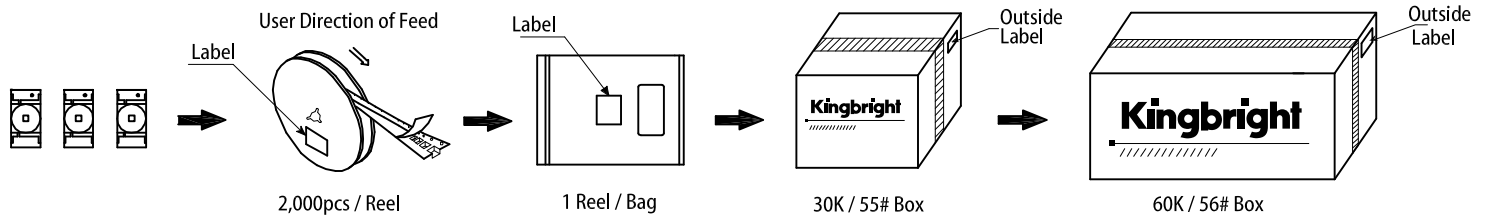


### REEL DIMENSION (units : mm)



- Notes:
1. Don't cause stress to the LEDs while it is exposed to high temperature.
  2. The maximum number of reflow soldering passes is 2 times.
  3. Reflow soldering is recommended. Other soldering methods are not recommended as they might cause damage to the product.

## PACKING & LABEL SPECIFICATIONS



Confidential

### PRECAUTIONARY NOTES

1. The information included in this document reflects representative usage scenarios and is intended for technical reference only.
2. The part number, type, and specifications mentioned in this document are subject to future change and improvement without notice. Before production usage customer should refer to the latest datasheet for the updated specifications.
3. When using the products referenced in this document, please make sure the product is being operated within the environmental and electrical limits specified in the datasheet. If customer usage exceeds the specified limits, Kingbright will not be responsible for any subsequent issues.
4. The information in this document applies to typical usage in consumer electronics applications. If customer's application has special reliability requirements or have life-threatening liabilities, such as automotive or medical usage, please consult with Kingbright representative for further assistance.
5. The contents and information of this document may not be reproduced or re-transmitted without permission by Kingbright.
6. All design applications should refer to Kingbright application notes available at <http://www.KingbrightUSA.com/ApplicationNotes>

## Данный компонент на территории Российской Федерации

### Вы можете приобрести в компании MosChip.

Для оперативного оформления запроса Вам необходимо перейти по данной ссылке:

<http://moschip.ru/get-element>

Вы можете разместить у нас заказ для любого Вашего проекта, будь то серийное производство или разработка единичного прибора.

В нашем ассортименте представлены ведущие мировые производители активных и пассивных электронных компонентов.

Нашей специализацией является поставка электронной компонентной базы двойного назначения, продукции таких производителей как XILINX, Intel (ex.ALTERA), Vicor, Microchip, Texas Instruments, Analog Devices, Mini-Circuits, Amphenol, Glenair.

Сотрудничество с глобальными дистрибьюторами электронных компонентов, предоставляет возможность заказывать и получать с международных складов практически любой перечень компонентов в оптимальные для Вас сроки.

На всех этапах разработки и производства наши партнеры могут получить квалифицированную поддержку опытных инженеров.

Система менеджмента качества компании отвечает требованиям в соответствии с ГОСТ Р ИСО 9001, ГОСТ РВ 0015-002 и ЭС РД 009

### Офис по работе с юридическими лицами:

105318, г.Москва, ул.Щербаковская д.3, офис 1107, 1118, ДЦ «Щербаковский»

Телефон: +7 495 668-12-70 (многоканальный)

Факс: +7 495 668-12-70 (доб.304)

E-mail: [info@moschip.ru](mailto:info@moschip.ru)

Skype отдела продаж:

moschip.ru

moschip.ru\_4

moschip.ru\_6

moschip.ru\_9